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CALIBRATION PROCEDURE IN MICROCHANNEL AMPLIFIERS DESIGN

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Abstract 1

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The main parameters of microchannel amplifiers - angular and energy distributions of photo- and secondary electron emission - are determined by the emission properties of materials. These parameters depend on the type of materials, the thickness of deposited films and the technology of processing their surfaces. Data on the emission properties of materials can be obtained by means of experimental measurements or by calculation methods using molecular dynamics. In both cases, this is associated with significant resource costs. In the cases where some of these characteristics of the materials are unknown, a calibration procedure can be recommended to determine them. Details of this procedure are described in this paper. Comparison of numerical and experimental data for specific devices is performed.

Keywords: Photo detector; Micro channel plate; Numerical simulation 11

1. INTRODUCTION

13 Microchannel amplifiers are widely used in astrophysics, medical diagnostics, accelerator physics, and night vision devices. They have many advantages: compactness, high gain, stable operation in radiation and in strong magnetic 14 fields. An amplifier consists of a photo cathode, one or more microchannel plates (MCP), an anode structure and high 15 16 speed electronic circuits that process signals at the output of the amplifier. Theoretical background of microchannel 17 amplifier simulations is described in ref. [1]. The computer simulation consists of two independent phases: microscopic 18 modeling and computation of the amplifier parameters.

The microscopic phase should determine the emission properties of materials used in the device. First, a 19 parameterized set of the secondary emission yield (SEY) dependencies in two variables, the energy of the primary 20 21 electron and the angle of incident electrons for lead glass should be developed. This parameterization can be done by 22 using results obtained from Monte Carlo calculations or from experimental measurements. As a result, it is necessary to 23 obtain the angular and energy distributions for secondary emission coefficient, as the parameters of the electron flux 24 incident on the surface of the material. Experimental measurements for the required characteristics are associated with 25 considerable time and resources of the measuring complex. It takes about three months for one sample [2-9].

26 The other way to get these data is computer simulation based on Monte-Carlo algorithms for the numerical models of molecular dynamics [10-14]. An example of numerical simulation using the code "CASINO" [15] is shown in Fig. 1, 27 where a beam of 10^5 electrons with random initial data falls on the surface with random positions of atoms at the angle 28 29 of 45°. Random data should represent the statistical properties of the interaction of a particle beam in the surface layer



Figure 1. Electron trajectories passing through a SiO2 multi-layer structure. Color shows the particle energy. of the material.

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